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CSD19535KTT

SLPS539B-MARCH 2015-REVISED JANUARY 2017

CSD19535KTT 100-V N-Channel NexFET™ Power MOSFET

1 Features

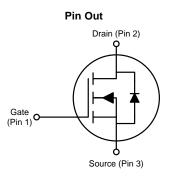
- Ultra-Low Q_q and Q_{qd}
- Low-Thermal Resistance
- Avalanche Rated
- Lead-Free Terminal Plating
- RoHS Compliant
- Halogen Free
- D²PAK Plastic Package

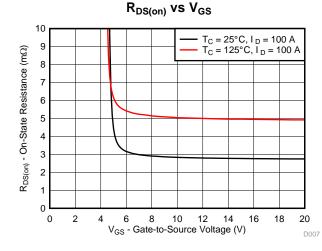
2 Applications

- Hot Swap
- Motor Control
- Secondary Side Synchronous Rectifier

3 Description

This 100-V, 2.8 m Ω , D²PAK (TO-263) NexFETTM power MOSFET is designed to minimize losses in power conversion applications.





Product Summary

T _A = 25°	C	TYPICAL VA	UNIT				
V _{DS}	Drain-to-Source Voltage 100						
Qg	Gate Charge Total (10 V)	arge Total (10 V) 75					
Q _{gd}	Gate Charge Gate-to-Drain	11	nC				
D	Drain-to-Source On Resistance	V _{GS} = 6 V 3.2		mΩ			
R _{DS(on)}	Drain-to-Source On Resistance	V _{GS} = 10 V 2.8		1112			
V _{GS(th)}	Threshold Voltage	2.7	V				

Device Information⁽¹⁾

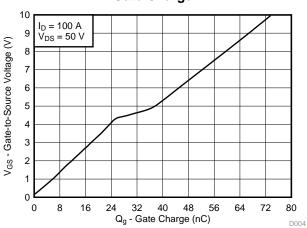
DEVICE QTY		MEDIA	PACKAGE	SHIP
CSD19535KTT	500		D ² PAK Plastic	Tape
CSD19535KTTT	50	13-Inch Reel	Package	and Reel

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Absolute Maximum Ratings

T _A = 2	25°C	VALUE	UNIT
V_{DS}	Drain-to-Source Voltage	100	V
V_{GS}	Gate-to-Source Voltage	±20	V
	Continuous Drain Current (Package Limited)	200	
I _D	Continuous Drain Current (Silicon Limited), $T_C = 25^{\circ}C$	197	A
	Continuous Drain Current (Silicon Limited), $T_{C} = 100^{\circ}C$	139	
I_{DM}	Pulsed Drain Current ⁽¹⁾	400	А
P_D	Power Dissipation, $T_C = 25^{\circ}C$	300	W
T _J , T _{stg}	Operating Junction, Storage Temperature	–55 to 175	ů
E _{AS}	Avalanche Energy, Single Pulse $I_D = 95 A, L = 0.1 mH$	451	mJ

(1) Max R_{0JC} = 0.5°C/W, pulse duration \leq 100 $\mu s,$ duty cycle \leq 1%.



Gate Charge

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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•	Added Community Resources

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5 Specifications

5.1 Electrical Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)

7	PARAMETER	TEST CONDITIONS	MIN TYP	MAX	UNIT
STATIC	CHARACTERISTICS		·		
BV_{DSS}	Drain-to-source voltage	$V_{GS} = 0 V, I_D = 250 \mu A$	100		V
I _{DSS}	Drain-to-source leakage current	$V_{GS} = 0 V, V_{DS} = 80 V$		1	μA
I _{GSS}	Gate-to-source leakage current	$V_{DS} = 0 V, V_{GS} = 20 V$		100	nA
V _{GS(th)}	Gate-to-source threshold voltage	$V_{DS} = V_{GS}, \ I_D = 250 \ \mu A$	2.2 2.7	3.4	V
D	Drain-to-source on resistance	V _{GS} = 6 V, I _D = 100 A	3.2	4.1	mΩ
R _{DS(on)}	Drain-to-source on resistance	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 100 \text{ A}$	2.8	3.4	11122
g _{fs}	Transconductance	V _{DS} = 10 V, I _D = 100 A	301		S
DYNAMI	C CHARACTERISTICS				
C _{iss}	Input capacitance		6100	7930	pF
C _{oss}	Output capacitance	V _{GS} = 0 V, V _{DS} = 50 V, <i>f</i> = 1 MHz	1160	1510	pF
C _{rss}	Reverse transfer capacitance		29	38	pF
R_{G}	Series gate resistance		1.4	2.8	Ω
Qg	Gate charge total (10 V)		75	98	nC
Q _{gd}	Gate charge gate-to-drain		11		nC
Q _{gs}	Gate charge gate-to-source	V _{DS} = 50 V, I _D = 100 A	25		nC
Q _{g(th)}	Gate charge at V _{th}		16		nC
Q _{oss}	Output charge	$V_{DS} = 50 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	210		nC
t _{d(on)}	Turnon delay time		9		ns
t _r	Rise time	V _{DS} = 50 V, V _{GS} = 10 V,	18		ns
t _{d(off)}	Turnoff delay time	$I_{DS} = 100 \text{ A}, \text{ R}_{G} = 0 \Omega$	21		ns
t _f	Fall time		15		ns
DIODE C	HARACTERISTICS		·		
V_{SD}	Diode forward voltage	I _{SD} = 100 A, V _{GS} = 0 V	0.9	1.1	V
Q _{rr}	Reverse recovery charge	V_{DS} = 50 V, I _F = 100 A,	435		nC
t _{rr}	Reverse recovery time	di/dt = 300 A/µs	85		ns

5.2 Thermal Information

 $T_A = 25^{\circ}C$ (unless otherwise stated)

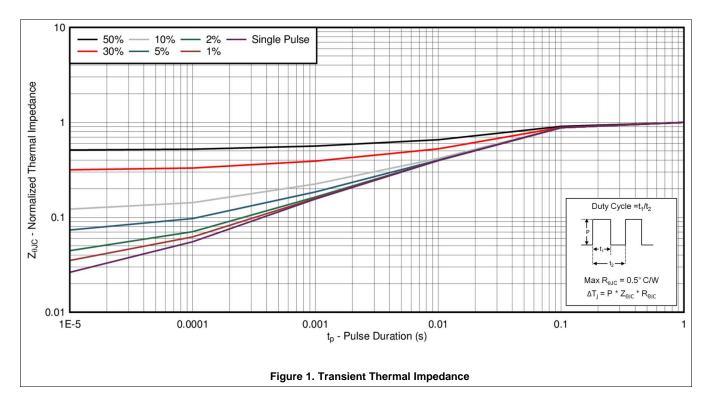
	THERMAL METRIC	MIN	TYP	MAX	UNIT
R_{\thetaJC}	Junction-to-case thermal resistance			0.5	°C/W
R_{\thetaJA}	Junction-to-ambient thermal resistance			62	°C/W

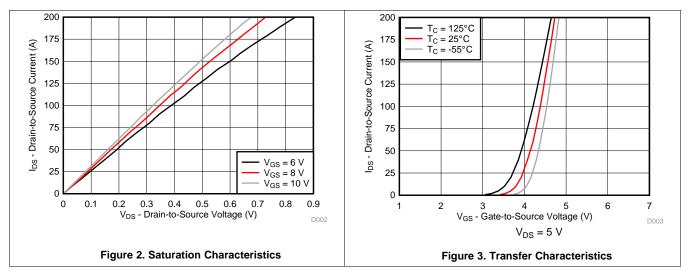
CSD19535KTT

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5.3 Typical MOSFET Characteristics

 $T_A = 25^{\circ}C$ (unless otherwise stated)





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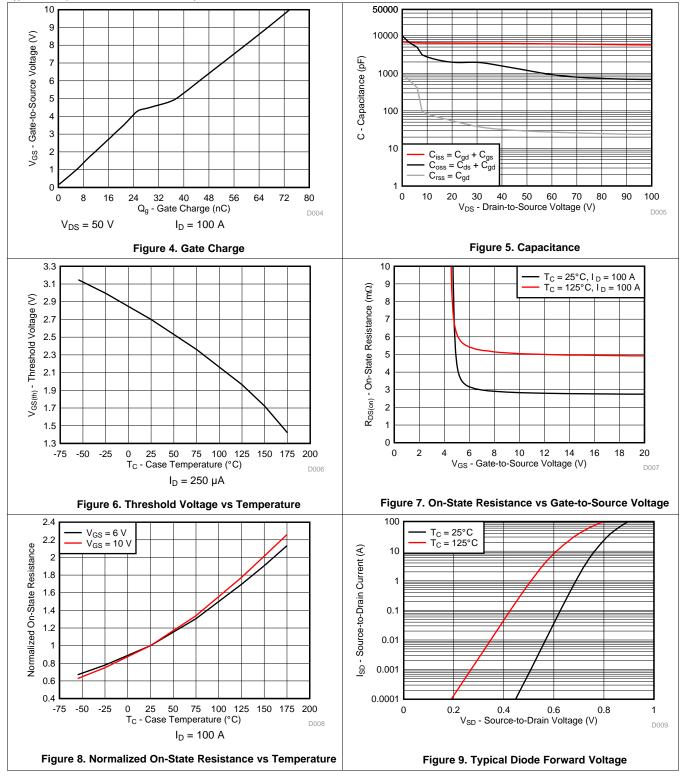


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Typical MOSFET Characteristics (continued)

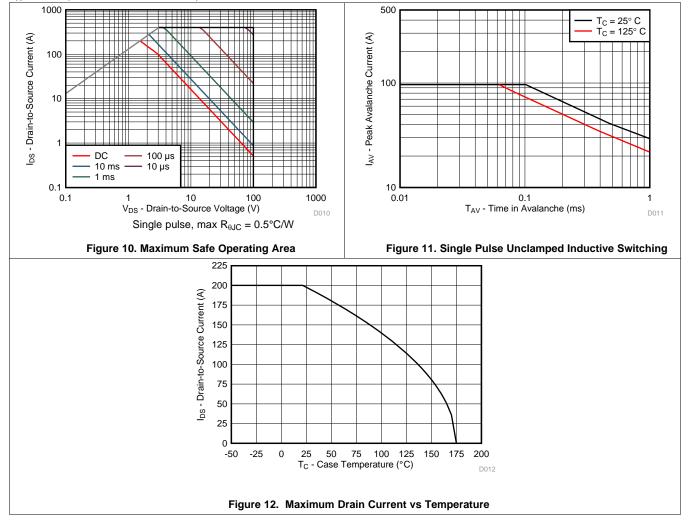
 $T_A = 25^{\circ}C$ (unless otherwise stated)





Typical MOSFET Characteristics (continued)

 $T_A = 25^{\circ}C$ (unless otherwise stated)



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6 Device and Documentation Support

6.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

6.2 Community Resources

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TI E2E[™] Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

6.3 Trademarks

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6.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

6.5 Glossary

SLYZ022 — TI Glossary.

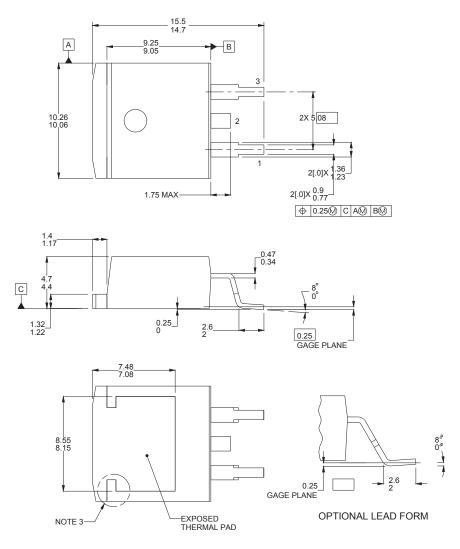
This glossary lists and explains terms, acronyms, and definitions.



7 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

7.1 KTT Package Dimensions



Notes:

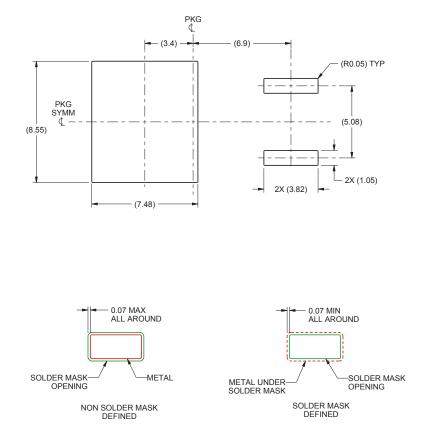
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. Features may not exist and shape may vary per different assembly sites.

	5
POSITION	DESIGNATION
Pin 1	Gate
Pin 2 / Tab	Drain
Pin 3	Source

Table 1. Pin Configuration

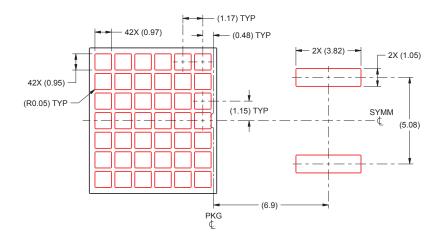


7.2 Recommended PCB Pattern



For recommended circuit layout for PCB designs, see *Reducing Ringing Through PCB Layout Techniques* (SLPA005).

7.3 Recommended Stencil Opening (0.125 mm Stencil Thickness)



Notes:

- 1. This package is designed to be soldered to a thermal pad on the board. See application notes *PowerPAD™ Thermally Enhanced Package* (SLMA002) and *PowerPAD™ Made Easy* (SLMA004) for more information.
- 2. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 3. Board assembly site may have different recommendations for stencil design.



11-Jan-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CSD19535KTT	ACTIVE	DDPAK/ TO-263	КТТ	3	500	Pb-Free (RoHS Exempt)	CU SN	Level-2-260C-1 YEAR		CSD19535KTT	Samples
CSD19535KTTT	ACTIVE	DDPAK/ TO-263	КТТ	3	50	Pb-Free (RoHS Exempt)	CU SN	Level-2-260C-1 YEAR		CSD19535KTT	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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11-Jan-2017

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